

# NX3L2267S

## Low-ohmic dual single-pole double-throw analog switch

Rev. 2 — 8 November 2011

Product data sheet

### 1. General description

The NX3L2267S is a dual low-ohmic single-pole double-throw analog switch suitable for use as an analog or digital 2 : 1 multiplexer/demultiplexer. Each switch has a digital select input (nS), two independent inputs/outputs (nY0 and nY1) and a common input/output (nZ).

The NX3L2267S includes termination resistors that improve noise immunity during overshoot excursions, off-isolation coupling, or pop-minimization.

Schmitt trigger action at the digital inputs makes the circuit tolerant to slower input rise and fall times. Low threshold digital inputs allows this device to be driven by 1.8 V logic levels in 3.3 V applications without significant increase in supply current  $I_{CC}$ . This makes it possible for the NX3L2267S to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation. The NX3L2267S allows signals with amplitude up to  $V_{CC}$  to be transmitted from nZ to nY0 or nY1, or from nY0 or nY1 to nZ. Its low ON resistance (0.5  $\Omega$ ) and flatness (0.13  $\Omega$ ) ensures minimal attenuation and distortion of transmitted signals.

### 2. Features and benefits

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
  - ◆ 1.65  $\Omega$  (typical) at  $V_{CC} = 1.4$  V
  - ◆ 0.95  $\Omega$  (typical) at  $V_{CC} = 1.65$  V
  - ◆ 0.55  $\Omega$  (typical) at  $V_{CC} = 2.3$  V
  - ◆ 0.50  $\Omega$  (typical) at  $V_{CC} = 2.7$  V
  - 0.50  $\Omega$  (typical) at  $V_{CC} = 4.3$  V
- Break-before-make switching
- High noise immunity
- ESD protection:
  - ◆ HBM JESD22-A114F Class 3A exceeds 7500 V
  - ◆ MM JESD22-A115-A exceeds 200 V
  - ◆ CDM AEC-Q100-011 revision B exceeds 1000 V
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD78B Class II Level A
- 1.8 V control logic at  $V_{CC} = 3.6$  V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below  $V_{CC}$
- High current handling capability (350 mA continuous current under 3.3 V supply)



- Specified from −40 °C to +85 °C and from −40 °C to +125 °C

3. Applications

- Cell phone
- PDA
- Portable media player

4. Ordering information

Table 1. Ordering information

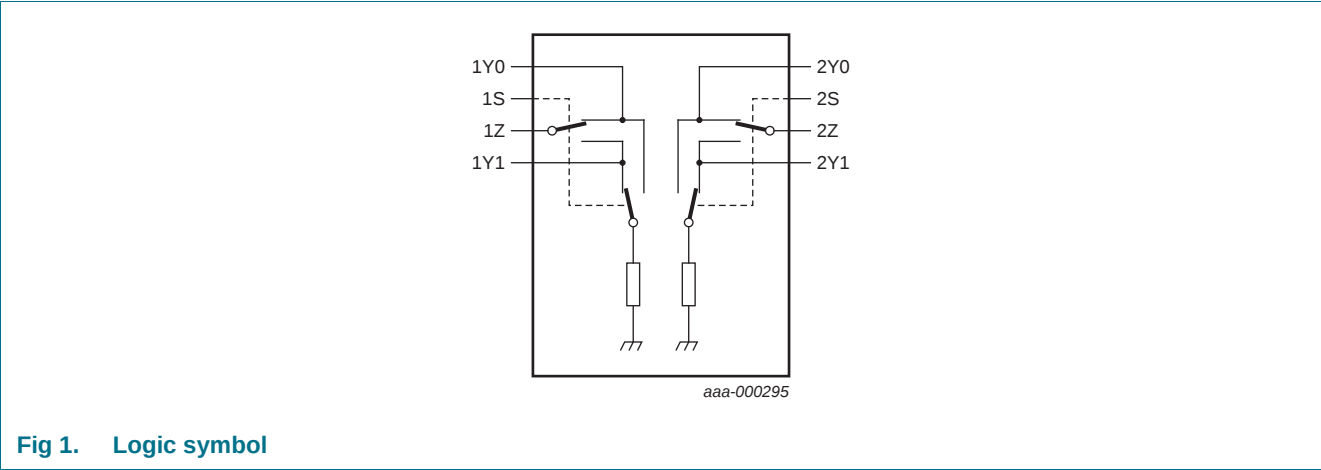
| Type number | Package           |        |                                                                                               |           |
|-------------|-------------------|--------|-----------------------------------------------------------------------------------------------|-----------|
|             | Temperature range | Name   | Description                                                                                   | Version   |
| NX3L2267SGU | −40 °C to +125 °C | XQFN10 | plastic, extremely thin quad flat package; no leads; 10 terminals; body 1.40 × 1.80 × 0.50 mm | SOT1160-1 |

5. Marking

Table 2. Marking

| Type number | Marking code |
|-------------|--------------|
| NX3L2267SGU | MS           |

6. Functional diagram



7. Pinning information

7.1 Pinning

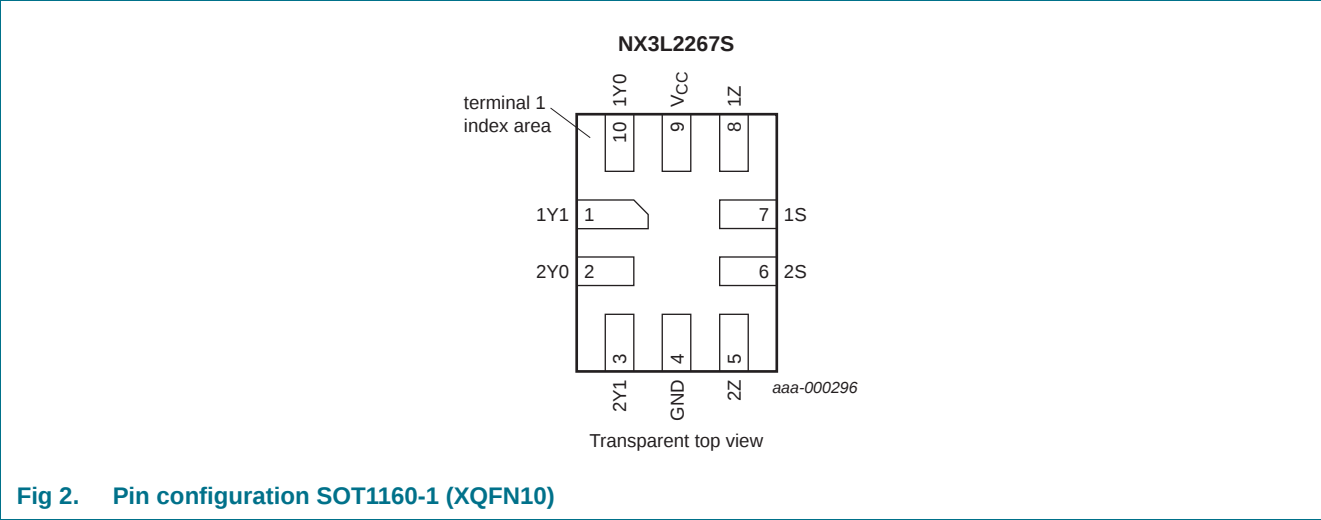


Fig 2. Pin configuration SOT1160-1 (XQFN10)

7.2 Pin description

Table 3. Pin description

| Symbol          | Pin | Description                 |
|-----------------|-----|-----------------------------|
| 1Y0             | 10  | independent input or output |
| 1Y1             | 1   | independent input or output |
| 2Y0             | 2   | independent input or output |
| 2Y1             | 3   | independent input or output |
| GND             | 4   | ground (0 V)                |
| 2Z              | 5   | common output or input      |
| 2S              | 6   | select input                |
| 1S              | 7   | select input                |
| 1Z              | 8   | common output or input      |
| V <sub>CC</sub> | 9   | supply voltage              |

## 8. Functional description

Table 4. Function table<sup>[1]</sup>

| Input nS | Channel on                      |
|----------|---------------------------------|
| L        | nY0 = nZ; nY1 terminated to GND |
| H        | nY1 = nZ; nY0 terminated to GND |

[1] H = HIGH voltage level; L = LOW voltage level.

## 9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol    | Parameter               | Conditions                                                                                                     | Min                 | Max            | Unit |
|-----------|-------------------------|----------------------------------------------------------------------------------------------------------------|---------------------|----------------|------|
| $V_{CC}$  | supply voltage          |                                                                                                                | -0.5                | +4.6           | V    |
| $V_I$     | input voltage           | select input nS                                                                                                | <sup>[1]</sup> -0.5 | +4.6           | V    |
| $V_{SW}$  | switch voltage          | nZ ON or OFF; nYn ON                                                                                           | <sup>[2]</sup> -0.5 | $V_{CC} + 0.5$ | V    |
|           |                         | nYn OFF                                                                                                        | 0                   | 1.4            | V    |
| $I_{IK}$  | input clamping current  | $V_I < -0.5$ V                                                                                                 | -50                 | -              | mA   |
| $I_{SK}$  | switch clamping current | $V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V                                                                       | -                   | $\pm 50$       | mA   |
| $I_{SW}$  | switch current          | $V_{SW} > -0.5$ V or $V_{SW} < V_{CC} + 0.5$ V;<br>source or sink current                                      | -                   | $\pm 350$      | mA   |
|           |                         | $V_{SW} > -0.5$ V or $V_{SW} < V_{CC} + 0.5$ V;<br>pulsed at 1 ms duration, < 10 % duty cycle;<br>peak current | -                   | $\pm 500$      | mA   |
| $T_{stg}$ | storage temperature     |                                                                                                                | -65                 | +150           | °C   |
| $P_{tot}$ | total power dissipation | $T_{amb} = -40$ °C to +125 °C                                                                                  | <sup>[3]</sup> -    | 250            | mW   |

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For XQFN10 package: above 133 °C the value of  $P_{tot}$  derates linearly with 11.5 mW/K.

## 10. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol              | Parameter                           | Conditions                | Min              | Max      | Unit |
|---------------------|-------------------------------------|---------------------------|------------------|----------|------|
| $V_{CC}$            | supply voltage                      |                           | 1.4              | 4.3      | V    |
| $V_I$               | input voltage                       | select input nS           | 0                | 4.3      | V    |
| $V_{SW}$            | switch voltage                      | switch input nY0 or nY1   | <sup>[1]</sup> 0 | $V_{CC}$ | V    |
| $T_{amb}$           | ambient temperature                 |                           | -40              | +125     | °C   |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CC} = 1.4$ V to 4.3 V | <sup>[2]</sup> - | 200      | ns/V |

[1] To avoid sinking GND current from terminal nZ when switch current flows in terminal nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no GND current will flow from terminal nYn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to select input nS signal levels.

## 11. Static characteristics

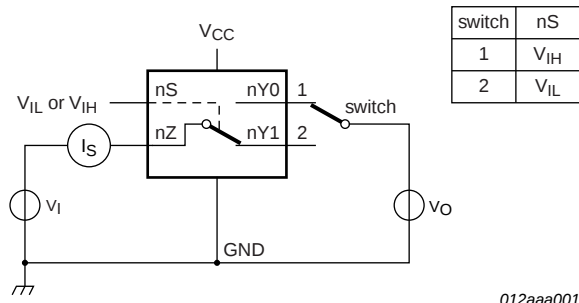
**Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

| Symbol              | Parameter                 | Conditions                                                                             | T <sub>amb</sub> = 25 °C |      |      | T <sub>amb</sub> = –40 °C to +125 °C |             |              | Unit |
|---------------------|---------------------------|----------------------------------------------------------------------------------------|--------------------------|------|------|--------------------------------------|-------------|--------------|------|
|                     |                           |                                                                                        | Min                      | Typ  | Max  | Min                                  | Max (85 °C) | Max (125 °C) |      |
| V <sub>IH</sub>     | HIGH-level input voltage  | V <sub>CC</sub> = 1.4 V to 1.6 V                                                       | 0.9                      | -    | -    | 0.9                                  | -           | -            | V    |
|                     |                           | V <sub>CC</sub> = 1.65 V to 1.95 V                                                     | 0.9                      | -    | -    | 0.9                                  | -           | -            | V    |
|                     |                           | V <sub>CC</sub> = 2.3 V to 2.7 V                                                       | 1.1                      | -    | -    | 1.1                                  | -           | -            | V    |
|                     |                           | V <sub>CC</sub> = 2.7 V to 3.6 V                                                       | 1.3                      | -    | -    | 1.3                                  | -           | -            | V    |
|                     |                           | V <sub>CC</sub> = 3.6 V to 4.3 V                                                       | 1.4                      | -    | -    | 1.4                                  | -           | -            | V    |
| V <sub>IL</sub>     | LOW-level input voltage   | V <sub>CC</sub> = 1.4 V to 1.6 V                                                       | -                        | -    | 0.3  | -                                    | 0.3         | 0.3          | V    |
|                     |                           | V <sub>CC</sub> = 1.65 V to 1.95 V                                                     | -                        | -    | 0.4  | -                                    | 0.4         | 0.3          | V    |
|                     |                           | V <sub>CC</sub> = 2.3 V to 2.7 V                                                       | -                        | -    | 0.5  | -                                    | 0.5         | 0.4          | V    |
|                     |                           | V <sub>CC</sub> = 2.7 V to 3.6 V                                                       | -                        | -    | 0.5  | -                                    | 0.5         | 0.5          | V    |
|                     |                           | V <sub>CC</sub> = 3.6 V to 4.3 V                                                       | -                        | -    | 0.6  | -                                    | 0.6         | 0.6          | V    |
| I <sub>I</sub>      | input leakage current     | select input nS;<br>V <sub>I</sub> = GND to 4.3 V;<br>V <sub>CC</sub> = 1.4 V to 4.3 V | -                        | -    | -    | -                                    | ±0.5        | ±1           | μA   |
| I <sub>S(ON)</sub>  | ON-state leakage current  | nZ port; see <a href="#">Figure 3</a><br>V <sub>CC</sub> = 1.4 V to 4.3 V              | -                        | -    | ±50  | -                                    | ±150        | ±1500        | nA   |
| I <sub>CC</sub>     | supply current            | V <sub>I</sub> = V <sub>CC</sub> or GND;<br>V <sub>SW</sub> = GND or V <sub>CC</sub>   |                          |      |      |                                      |             |              |      |
|                     |                           | V <sub>CC</sub> = 3.6 V                                                                | -                        | -    | 100  | -                                    | 300         | 3000         | nA   |
|                     |                           | V <sub>CC</sub> = 4.3 V                                                                | -                        | -    | 150  | -                                    | 500         | 5000         | nA   |
| ΔI <sub>CC</sub>    | additional supply current | V <sub>SW</sub> = GND or V <sub>CC</sub>                                               |                          |      |      |                                      |             |              |      |
|                     |                           | V <sub>I</sub> = 2.6 V; V <sub>CC</sub> = 4.3 V                                        | -                        | 2.0  | 4.0  | -                                    | 7           | 7            | μA   |
|                     |                           | V <sub>I</sub> = 2.6 V; V <sub>CC</sub> = 3.6 V                                        | -                        | 0.35 | 0.7  | -                                    | 1           | 1            | μA   |
|                     |                           | V <sub>I</sub> = 1.8 V; V <sub>CC</sub> = 4.3 V                                        | -                        | 7.0  | 10.0 | -                                    | 15          | 15           | μA   |
|                     |                           | V <sub>I</sub> = 1.8 V; V <sub>CC</sub> = 3.6 V                                        | -                        | 2.5  | 4.0  | -                                    | 5           | 5            | μA   |
|                     |                           | V <sub>I</sub> = 1.8 V; V <sub>CC</sub> = 2.5 V                                        | -                        | 50   | 200  | -                                    | 300         | 500          | nA   |
| R <sub>T</sub>      | termination resistance    | V <sub>SW</sub> = 1.0 V; V <sub>CC</sub> = 3.0 V <a href="#">[1]</a>                   | -                        | 200  | -    | -                                    | -           | -            | Ω    |
| C <sub>I</sub>      | input capacitance         |                                                                                        | -                        | 1.0  | -    | -                                    | -           | -            | pF   |
| C <sub>S(OFF)</sub> | OFF-state capacitance     | port nYn                                                                               | -                        | 35   | -    | -                                    | -           | -            | pF   |
| C <sub>S(ON)</sub>  | ON-state capacitance      | port nYn                                                                               | -                        | 135  | -    | -                                    | -           | -            | pF   |

[1] Guaranteed by characterization, not production tested.

## 11.1 Test circuits



$V_I = 0.3 \text{ V}$  or  $V_{CC} - 0.3 \text{ V}$ ;  $V_O = V_{CC} - 0.3 \text{ V}$  or  $0.3 \text{ V}$ .

**Fig 3. Test circuit for measuring ON-state leakage current**

## 11.2 ON resistance

**Table 8. ON resistance**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see [Figure 5](#) to [Figure 11](#).

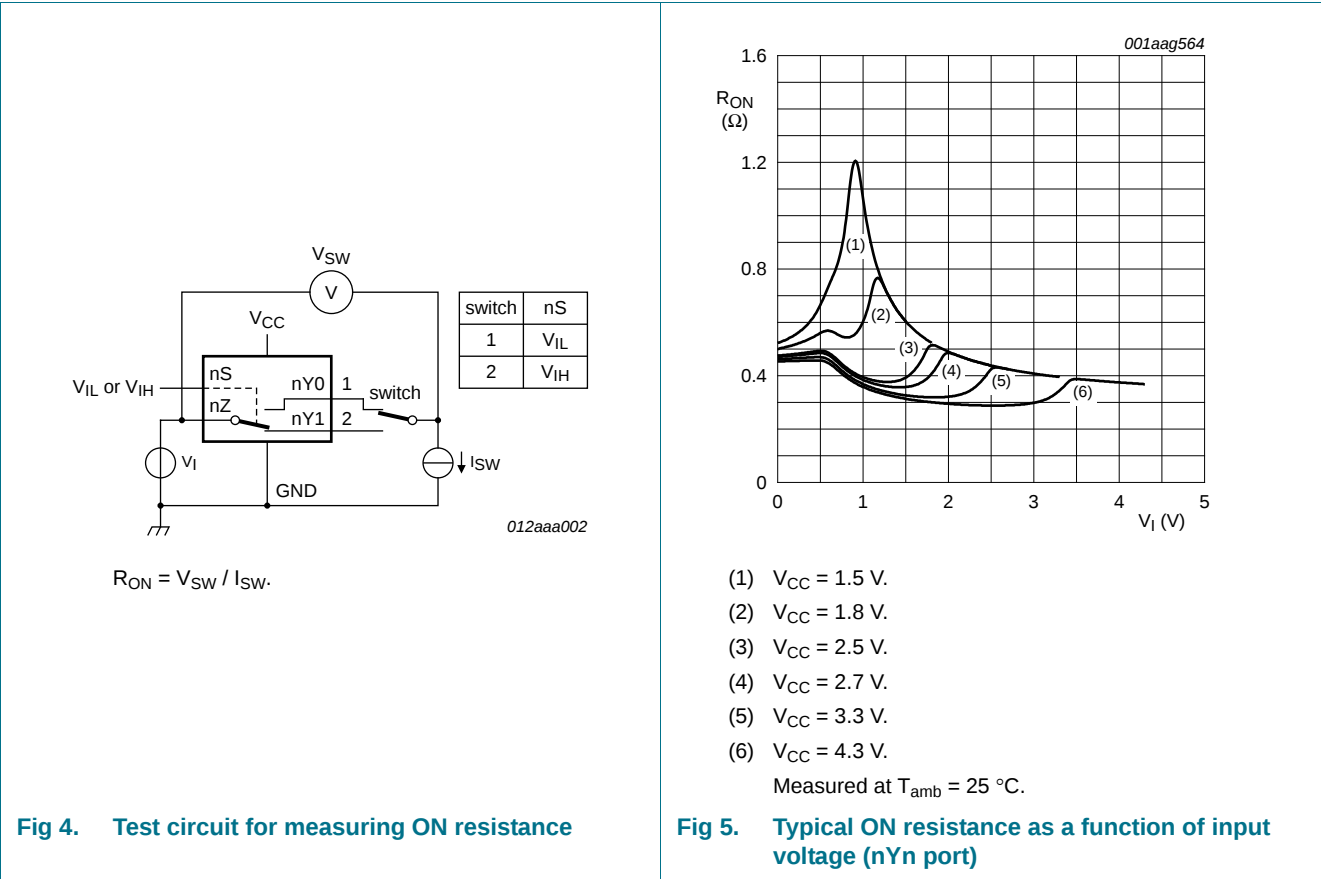
| Symbol          | Parameter                               | Conditions                                                                                                  | -40 °C to +85 °C |                    |       | -40 °C to +125 °C |      | Unit     |
|-----------------|-----------------------------------------|-------------------------------------------------------------------------------------------------------------|------------------|--------------------|-------|-------------------|------|----------|
|                 |                                         |                                                                                                             | Min              | Typ <sup>[1]</sup> | Max   | Min               | Max  |          |
| $R_{ON(peak)}$  | ON resistance (peak)                    | port nYn;<br>$V_I = \text{GND to } V_{CC}$ ;<br>$I_{SW} = 100 \text{ mA}$ ;<br>see <a href="#">Figure 4</a> |                  |                    |       |                   |      |          |
|                 |                                         | $V_{CC} = 1.4 \text{ V}$                                                                                    | -                | 1.65               | 3.7   | -                 | 4.1  | $\Omega$ |
|                 |                                         | $V_{CC} = 1.65 \text{ V}$                                                                                   | -                | 0.95               | 1.6   | -                 | 1.7  | $\Omega$ |
|                 |                                         | $V_{CC} = 2.3 \text{ V}$                                                                                    | -                | 0.55               | 0.8   | -                 | 0.9  | $\Omega$ |
|                 |                                         | $V_{CC} = 2.7 \text{ V}$                                                                                    | -                | 0.50               | 0.75  | -                 | 0.9  | $\Omega$ |
|                 |                                         | $V_{CC} = 4.3 \text{ V}$                                                                                    | -                | 0.50               | 0.75  | -                 | 0.9  | $\Omega$ |
| $\Delta R_{ON}$ | ON resistance mismatch between channels | $V_I = \text{GND to } V_{CC}$ ;<br>$I_{SW} = 100 \text{ mA}$                                                |                  |                    |       |                   |      |          |
|                 |                                         | $V_{CC} = 1.4 \text{ V}$                                                                                    | -                | 0.20               | 0.35  | -                 | 0.35 | $\Omega$ |
|                 |                                         | $V_{CC} = 1.65 \text{ V}$                                                                                   | -                | 0.20               | 0.25  | -                 | 0.30 | $\Omega$ |
|                 |                                         | $V_{CC} = 2.3 \text{ V}$                                                                                    | -                | 0.09               | 0.13  | -                 | 0.15 | $\Omega$ |
|                 |                                         | $V_{CC} = 2.7 \text{ V}$                                                                                    | -                | 0.09               | 0.125 | -                 | 0.15 | $\Omega$ |
|                 |                                         | $V_{CC} = 4.3 \text{ V}$                                                                                    | -                | 0.09               | 0.125 | -                 | 0.15 | $\Omega$ |

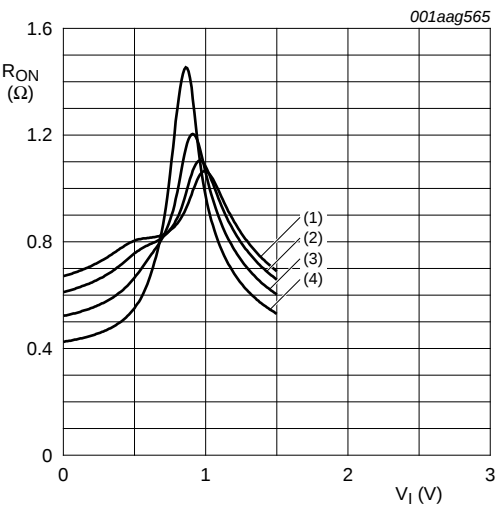
**Table 8. ON resistance ...continued**  
 At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see [Figure 5](#) to [Figure 11](#).

| Symbol                | Parameter                | Conditions                                                                         | –40 °C to +85 °C |                    |      | –40 °C to +125 °C |      | Unit |
|-----------------------|--------------------------|------------------------------------------------------------------------------------|------------------|--------------------|------|-------------------|------|------|
|                       |                          |                                                                                    | Min              | Typ <sup>[1]</sup> | Max  | Min               | Max  |      |
| R <sub>ON(flat)</sub> | ON resistance (flatness) | port nYn;<br>V <sub>I</sub> = GND to V <sub>CC</sub> ;<br>I <sub>SW</sub> = 100 mA | <sup>[3]</sup>   |                    |      |                   |      |      |
|                       |                          | V <sub>CC</sub> = 1.4 V                                                            | -                | 1.05               | 3.35 | -                 | 3.65 | Ω    |
|                       |                          | V <sub>CC</sub> = 1.65 V                                                           | -                | 0.55               | 1.25 | -                 | 1.35 | Ω    |
|                       |                          | V <sub>CC</sub> = 2.3 V                                                            | -                | 0.20               | 0.35 | -                 | 0.40 | Ω    |
|                       |                          | V <sub>CC</sub> = 2.7 V                                                            | -                | 0.18               | 0.35 | -                 | 0.40 | Ω    |
|                       |                          | V <sub>CC</sub> = 4.3 V                                                            | -                | 0.23               | 0.40 | -                 | 0.45 | Ω    |

- [1] Typical values are measured at  $T_{amb} = 25 \text{ }^{\circ}\text{C}$ .
- [2] Measured at identical  $V_{CC}$ , temperature and input voltage.
- [3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical  $V_{CC}$  and temperature.

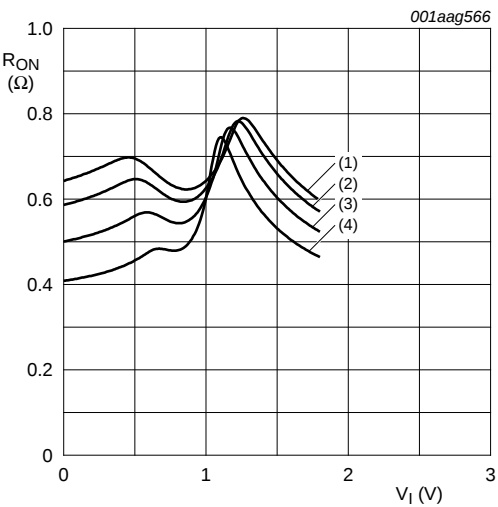
11.3 ON resistance test circuit and graphs





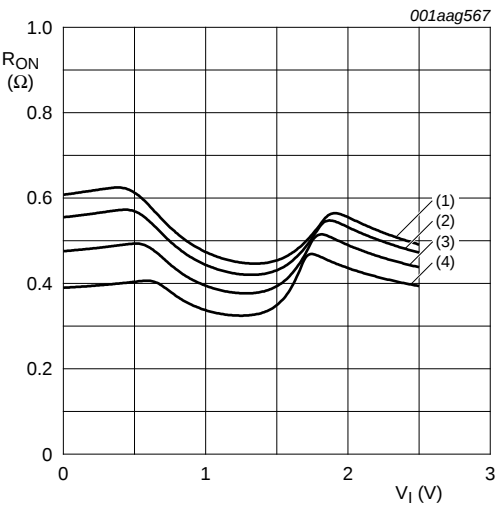
- (1)  $T_{amb} = 125\text{ }^{\circ}\text{C}.$
- (2)  $T_{amb} = 85\text{ }^{\circ}\text{C}.$
- (3)  $T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (4)  $T_{amb} = -40\text{ }^{\circ}\text{C}.$

Fig 6. ON resistance as a function of input voltage;  
 $V_{CC} = 1.5\text{ V}$  (nYn port)



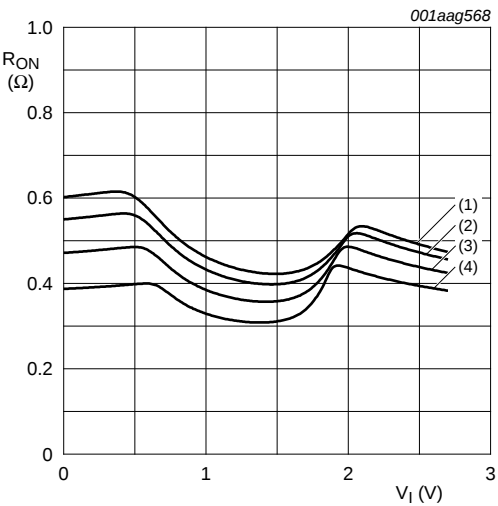
- (1)  $T_{amb} = 125\text{ }^{\circ}\text{C}.$
- (2)  $T_{amb} = 85\text{ }^{\circ}\text{C}.$
- (3)  $T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (4)  $T_{amb} = -40\text{ }^{\circ}\text{C}.$

Fig 7. ON resistance as a function of input voltage;  
 $V_{CC} = 1.8\text{ V}$  (nYn port)



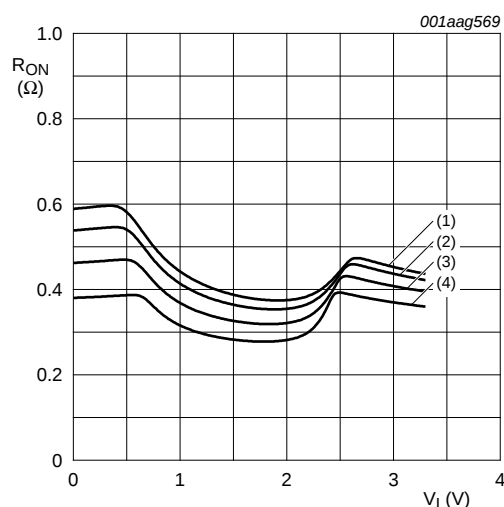
- (1)  $T_{amb} = 125\text{ }^{\circ}\text{C}.$
- (2)  $T_{amb} = 85\text{ }^{\circ}\text{C}.$
- (3)  $T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (4)  $T_{amb} = -40\text{ }^{\circ}\text{C}.$

Fig 8. ON resistance as a function of input voltage;  
 $V_{CC} = 2.5\text{ V}$  (nYn port)



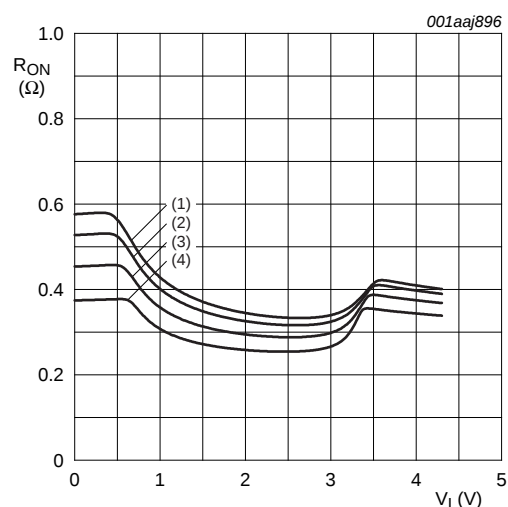
- (1)  $T_{amb} = 125\text{ }^{\circ}\text{C}.$
- (2)  $T_{amb} = 85\text{ }^{\circ}\text{C}.$
- (3)  $T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (4)  $T_{amb} = -40\text{ }^{\circ}\text{C}.$

Fig 9. ON resistance as a function of input voltage;  
 $V_{CC} = 2.7\text{ V}$  (nYn port)



- (1)  $T_{amb} = 125\text{ }^{\circ}\text{C}$ .
- (2)  $T_{amb} = 85\text{ }^{\circ}\text{C}$ .
- (3)  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .
- (4)  $T_{amb} = -40\text{ }^{\circ}\text{C}$ .

**Fig 10.** ON resistance as a function of input voltage;  
 $V_{CC} = 3.3\text{ V}$



- (1)  $T_{amb} = 125\text{ }^{\circ}\text{C}$ .
- (2)  $T_{amb} = 85\text{ }^{\circ}\text{C}$ .
- (3)  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .
- (4)  $T_{amb} = -40\text{ }^{\circ}\text{C}$ .

**Fig 11.** ON resistance as a function of input voltage;  
 $V_{CC} = 4.3\text{ V}$

## 12. Dynamic characteristics

**Table 9.** Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see [Figure 14](#).

| Symbol    | Parameter    | Conditions                                        | $T_{amb} = 25\text{ }^{\circ}\text{C}$ |                    |     | $T_{amb} = -40\text{ }^{\circ}\text{C to } +125\text{ }^{\circ}\text{C}$ |             |              | Unit |
|-----------|--------------|---------------------------------------------------|----------------------------------------|--------------------|-----|--------------------------------------------------------------------------|-------------|--------------|------|
|           |              |                                                   | Min                                    | Typ <sup>[1]</sup> | Max | Min                                                                      | Max (85 °C) | Max (125 °C) |      |
| $t_{en}$  | enable time  | nS to nZ or nYn;<br>see <a href="#">Figure 12</a> |                                        |                    |     |                                                                          |             |              |      |
|           |              | $V_{CC} = 1.4\text{ V to } 1.6\text{ V}$          | -                                      | 50                 | 90  | -                                                                        | 120         | 120          | ns   |
|           |              | $V_{CC} = 1.65\text{ V to } 1.95\text{ V}$        | -                                      | 36                 | 70  | -                                                                        | 80          | 90           | ns   |
|           |              | $V_{CC} = 2.3\text{ V to } 2.7\text{ V}$          | -                                      | 24                 | 45  | -                                                                        | 50          | 55           | ns   |
|           |              | $V_{CC} = 2.7\text{ V to } 3.6\text{ V}$          | -                                      | 22                 | 40  | -                                                                        | 45          | 50           | ns   |
|           |              | $V_{CC} = 3.6\text{ V to } 4.3\text{ V}$          | -                                      | 22                 | 40  | -                                                                        | 45          | 50           | ns   |
| $t_{dis}$ | disable time | nS to nZ or nYn;<br>see <a href="#">Figure 12</a> |                                        |                    |     |                                                                          |             |              |      |
|           |              | $V_{CC} = 1.4\text{ V to } 1.6\text{ V}$          | -                                      | 32                 | 70  | -                                                                        | 80          | 90           | ns   |
|           |              | $V_{CC} = 1.65\text{ V to } 1.95\text{ V}$        | -                                      | 20                 | 55  | -                                                                        | 60          | 65           | ns   |
|           |              | $V_{CC} = 2.3\text{ V to } 2.7\text{ V}$          | -                                      | 12                 | 25  | -                                                                        | 30          | 35           | ns   |
|           |              | $V_{CC} = 2.7\text{ V to } 3.6\text{ V}$          | -                                      | 10                 | 20  | -                                                                        | 25          | 30           | ns   |
|           |              | $V_{CC} = 3.6\text{ V to } 4.3\text{ V}$          | -                                      | 10                 | 20  | -                                                                        | 25          | 30           | ns   |

Table 9. Dynamic characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 14.

| Symbol           | Parameter              | Conditions                         | T <sub>amb</sub> = 25 °C |                    |     | T <sub>amb</sub> = –40 °C to +125 °C |             |              | Unit |
|------------------|------------------------|------------------------------------|--------------------------|--------------------|-----|--------------------------------------|-------------|--------------|------|
|                  |                        |                                    | Min                      | Typ <sup>[1]</sup> | Max | Min                                  | Max (85 °C) | Max (125 °C) |      |
| t <sub>b-m</sub> | break-before-make time | see Figure 13                      |                          |                    |     |                                      |             |              |      |
|                  |                        |                                    |                          | [2]                |     |                                      |             |              |      |
|                  |                        | V <sub>CC</sub> = 1.4 V to 1.6 V   | -                        | 19                 | -   | 9                                    | -           | -            | ns   |
|                  |                        | V <sub>CC</sub> = 1.65 V to 1.95 V | -                        | 17                 | -   | 7                                    | -           | -            | ns   |
|                  |                        | V <sub>CC</sub> = 2.3 V to 2.7 V   | -                        | 13                 | -   | 4                                    | -           | -            | ns   |
|                  |                        | V <sub>CC</sub> = 2.7 V to 3.6 V   | -                        | 10                 | -   | 3                                    | -           | -            | ns   |
|                  |                        | V <sub>CC</sub> = 3.6 V to 4.3 V   | -                        | 10                 | -   | 2                                    | -           | -            | ns   |

[1] Typical values are measured at T<sub>amb</sub> = 25 °C and V<sub>CC</sub> = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

[2] Break-before-make guaranteed by design.

12.1 Waveform and test circuits

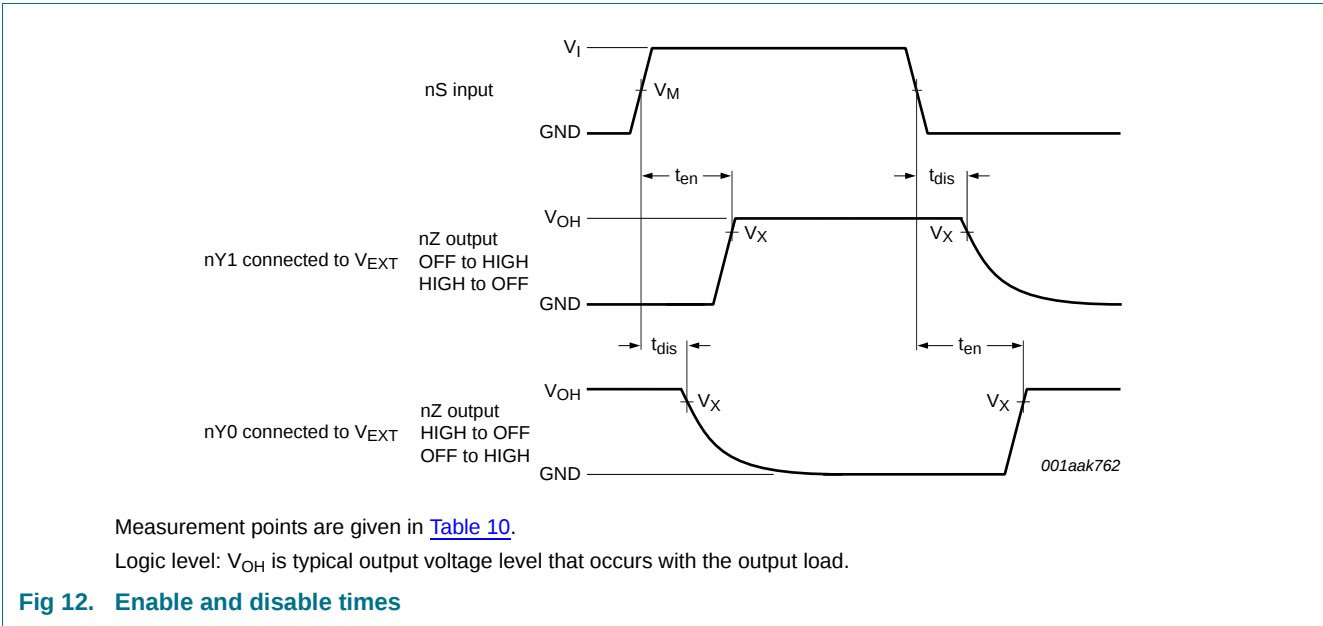


Table 10. Measurement points

| Supply voltage  | Input              | Output             |
|-----------------|--------------------|--------------------|
| V <sub>CC</sub> | V <sub>M</sub>     | V <sub>X</sub>     |
| 1.4 V to 4.3 V  | 0.5V <sub>CC</sub> | 0.9V <sub>OH</sub> |

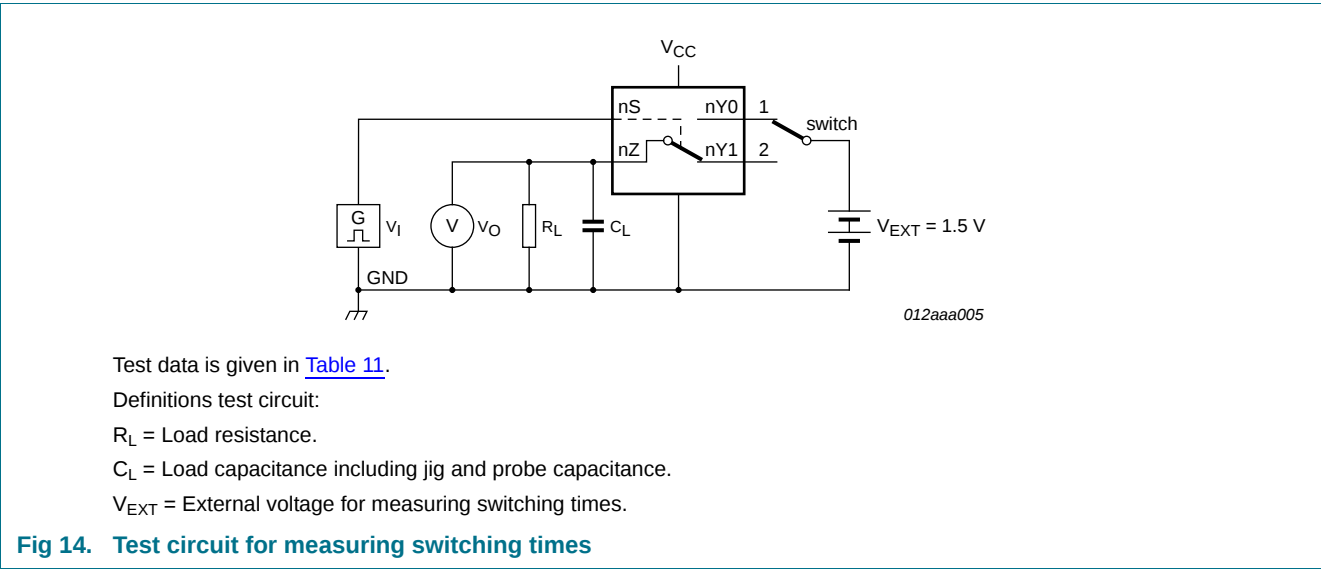
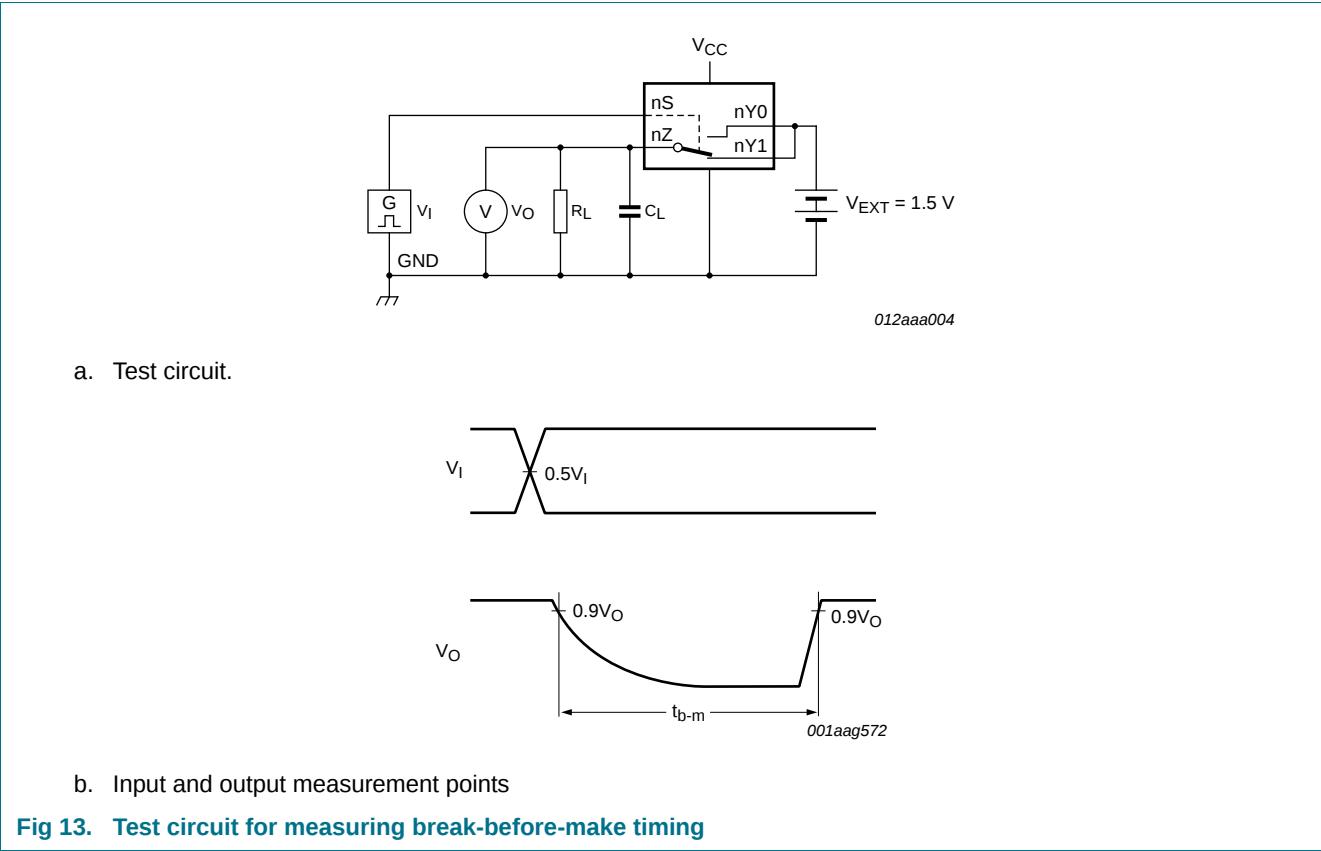


Table 11. Test data

| Supply voltage | Input    |               | Load  |             |
|----------------|----------|---------------|-------|-------------|
| $V_{CC}$       | $V_I$    | $t_r, t_f$    | $C_L$ | $R_L$       |
| 1.4 V to 4.3 V | $V_{CC}$ | $\leq 2.5$ ns | 35 pF | 50 $\Omega$ |

## 12.2 Additional dynamic characteristics

**Table 12. Additional dynamic characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $V_I$  = GND or  $V_{CC}$  (unless otherwise specified);  $t_r = t_f \leq 2.5$  ns.

| Symbol         | Parameter                 | Conditions                                                                                                                                                        | $T_{amb} = 25\text{ °C}$ |      |     | Unit |
|----------------|---------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------|------|-----|------|
|                |                           |                                                                                                                                                                   | Min                      | Typ  | Max |      |
| THD            | total harmonic distortion | $f_i = 20\text{ Hz to }20\text{ kHz}$ ; $R_L = 32\text{ }\Omega$ ; see <a href="#">Figure 15</a> <sup>[1]</sup>                                                   |                          |      |     |      |
|                |                           | $V_{CC} = 1.4\text{ V}$ ; $V_I = 1\text{ V (p-p)}$                                                                                                                | -                        | 0.15 | -   | %    |
|                |                           | $V_{CC} = 1.65\text{ V}$ ; $V_I = 1.2\text{ V (p-p)}$                                                                                                             | -                        | 0.10 | -   | %    |
|                |                           | $V_{CC} = 2.3\text{ V}$ ; $V_I = 1.5\text{ V (p-p)}$                                                                                                              | -                        | 0.02 | -   | %    |
|                |                           | $V_{CC} = 2.7\text{ V}$ ; $V_I = 2\text{ V (p-p)}$                                                                                                                | -                        | 0.02 | -   | %    |
|                |                           | $V_{CC} = 4.3\text{ V}$ ; $V_I = 2\text{ V (p-p)}$                                                                                                                | -                        | 0.02 | -   | %    |
|                |                           | $V_{CC} = 3.0\text{ V}$ ; $V_I = 1\text{ V (p-p)}$ ; $R_L = 600\text{ }\Omega$                                                                                    | -                        | 0.01 | -   | %    |
| $f_{(-3dB)}$   | –3 dB frequency response  | $R_L = 50\text{ }\Omega$ ; see <a href="#">Figure 16</a> <sup>[1]</sup>                                                                                           |                          |      |     |      |
|                |                           | port nYn; $V_{CC} = 1.4\text{ V to }4.3\text{ V}$                                                                                                                 | -                        | 60   | -   | MHz  |
| $\alpha_{iso}$ | isolation (OFF-state)     | $f_i = 100\text{ kHz}$ ; $R_L = 50\text{ }\Omega$ ; see <a href="#">Figure 17</a> <sup>[1]</sup>                                                                  |                          |      |     |      |
|                |                           | $V_{CC} = 1.4\text{ V to }4.3\text{ V}$                                                                                                                           | -                        | –90  | -   | dB   |
| $V_{ct}$       | crosstalk voltage         | between digital inputs and switch;<br>$f_i = 1\text{ MHz}$ ; $C_L = 50\text{ pF}$ ; $R_L = 50\text{ }\Omega$ ; see <a href="#">Figure 18</a>                      |                          |      |     |      |
|                |                           | $V_{CC} = 1.4\text{ V to }3.6\text{ V}$                                                                                                                           | -                        | 0.21 | -   | V    |
|                |                           | $V_{CC} = 3.6\text{ V to }4.3\text{ V}$                                                                                                                           | -                        | 0.30 | -   | V    |
| Xtalk          | crosstalk                 | between switches; <sup>[1]</sup><br>$f_i = 100\text{ kHz}$ ; $R_L = 50\text{ }\Omega$ ; see <a href="#">Figure 19</a>                                             |                          |      |     |      |
|                |                           | $V_{CC} = 1.4\text{ V to }4.3\text{ V}$                                                                                                                           | -                        | –90  | -   | dB   |
| $Q_{inj}$      | charge injection          | $f_i = 1\text{ MHz}$ ; $C_L = 0.1\text{ nF}$ ; $R_L = 1\text{ M}\Omega$ ; $V_{gen} = 0\text{ V}$ ;<br>$R_{gen} = 0\text{ }\Omega$ ; see <a href="#">Figure 20</a> |                          |      |     |      |
|                |                           | $V_{CC} = 1.5\text{ V}$                                                                                                                                           | -                        | 4    | -   | pC   |
|                |                           | $V_{CC} = 1.8\text{ V}$                                                                                                                                           | -                        | 6    | -   | pC   |
|                |                           | $V_{CC} = 2.5\text{ V}$                                                                                                                                           | -                        | 16   | -   | pC   |
|                |                           | $V_{CC} = 3.3\text{ V}$                                                                                                                                           | -                        | 24   | -   | pC   |
|                |                           | $V_{CC} = 4.3\text{ V}$                                                                                                                                           | -                        | 37   | -   | pC   |

[1]  $f_i$  is biased at  $0.5V_{CC}$ .

12.3 Test circuits

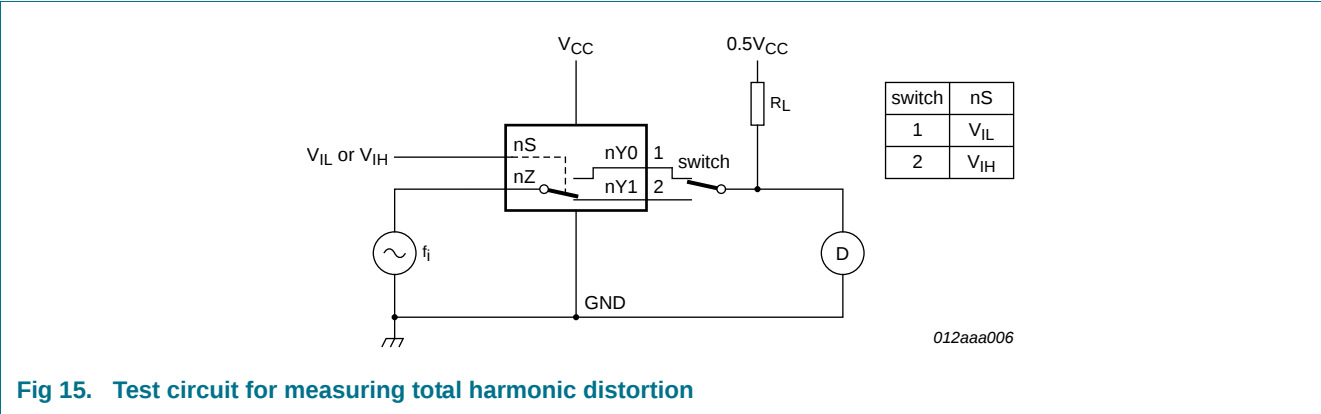


Fig 15. Test circuit for measuring total harmonic distortion

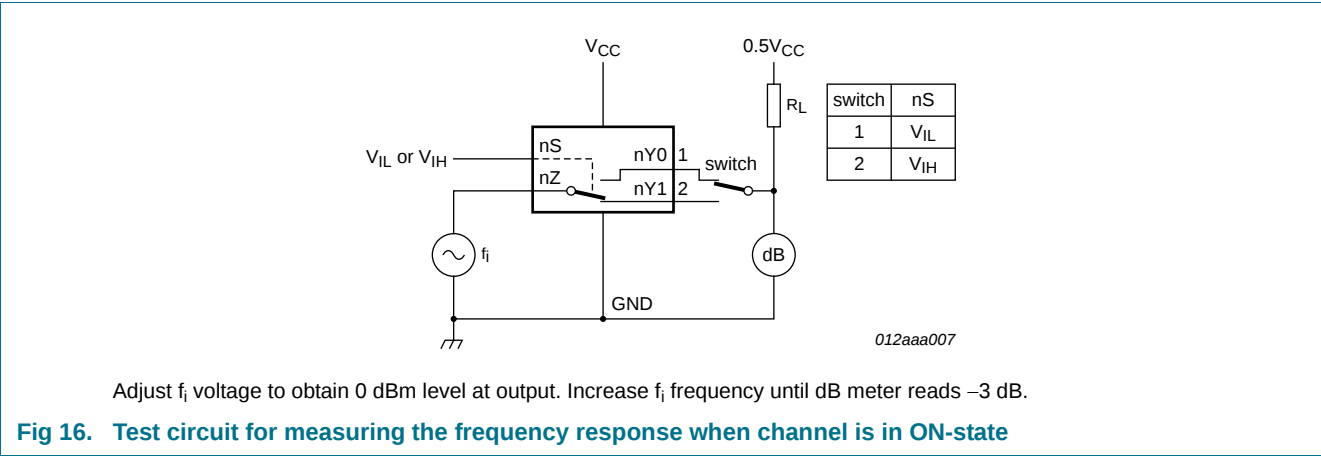


Fig 16. Test circuit for measuring the frequency response when channel is in ON-state

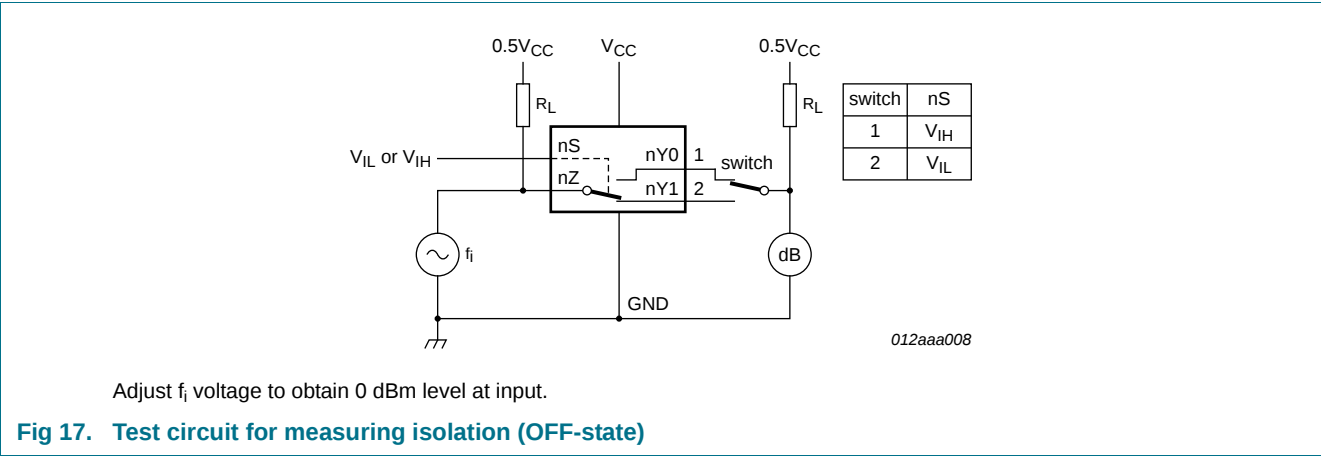
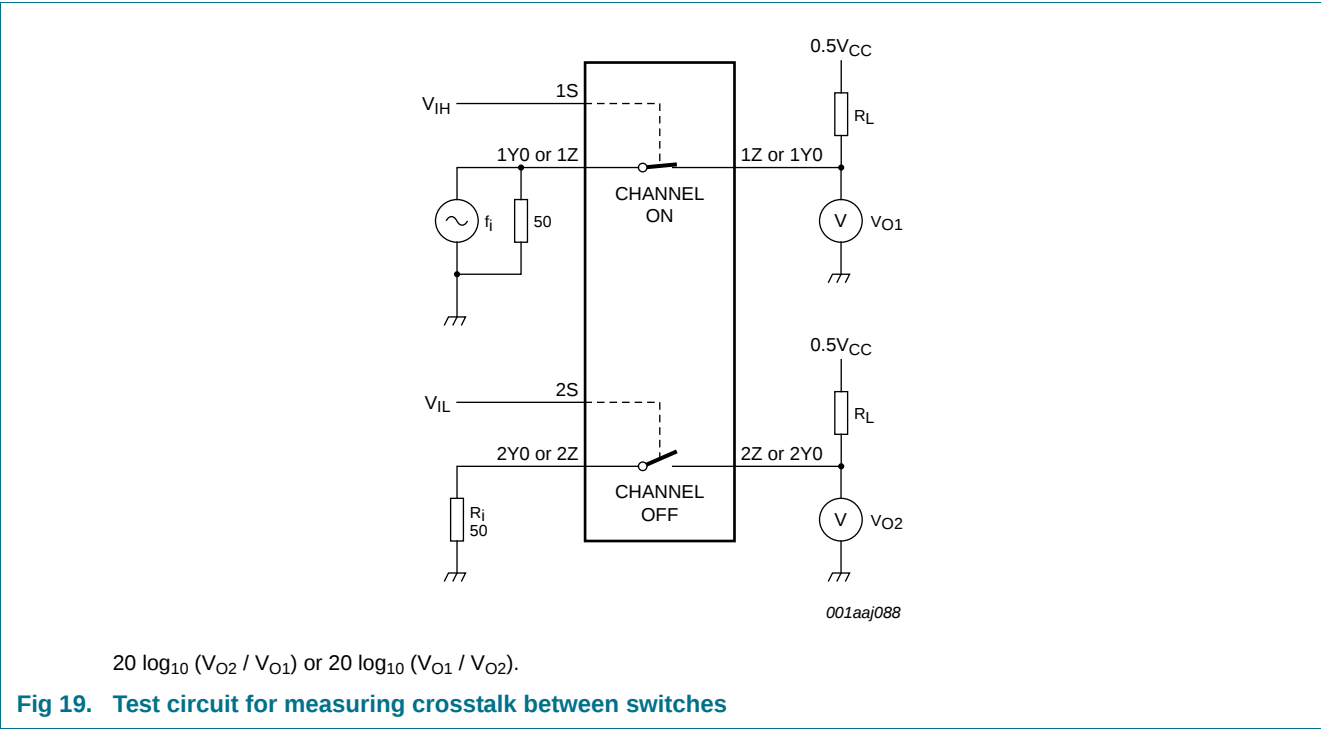
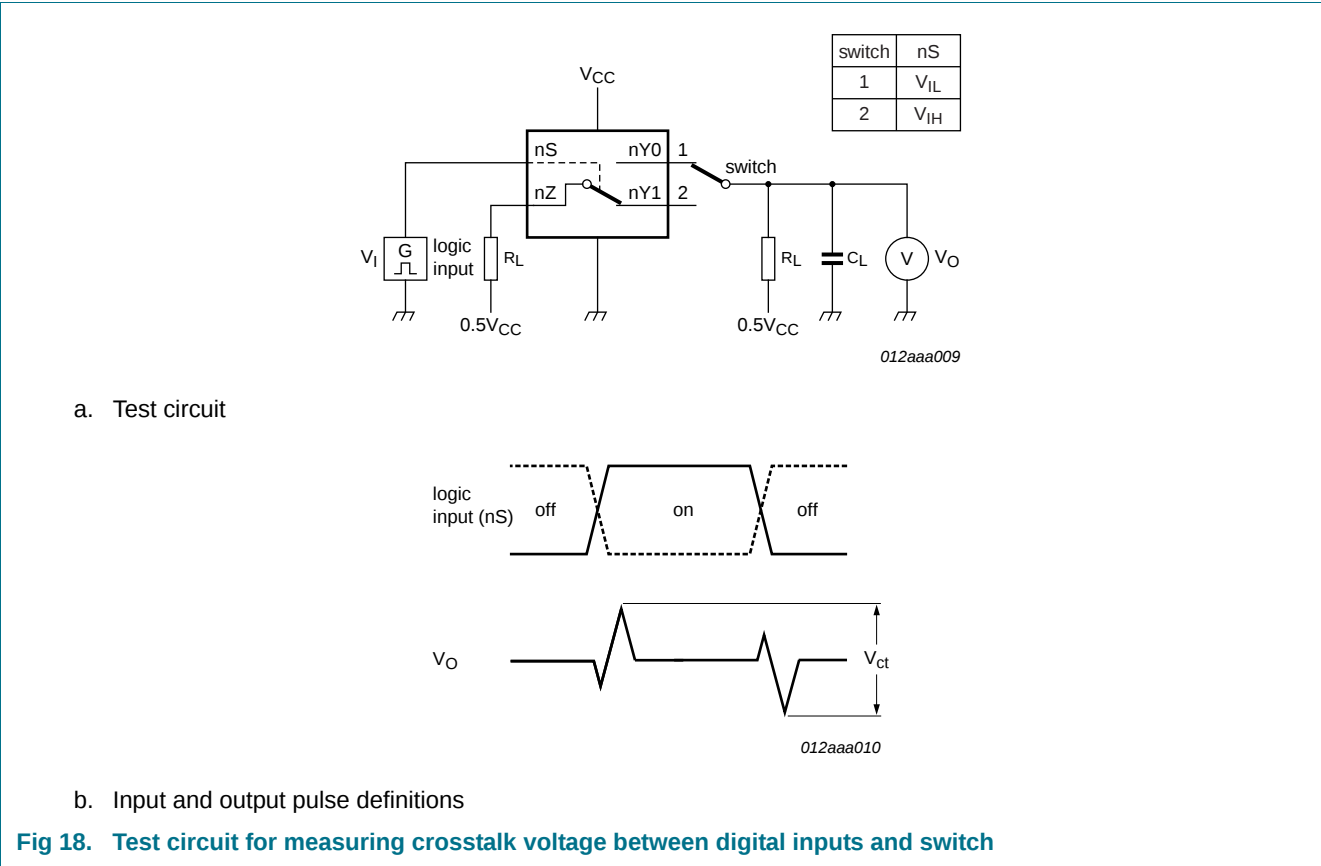
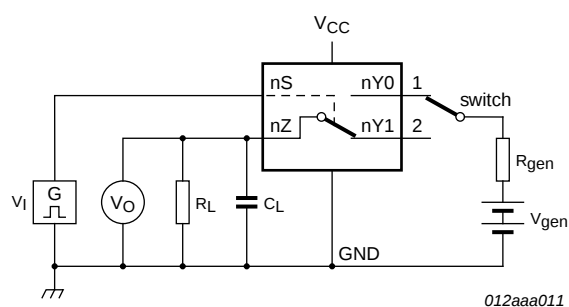
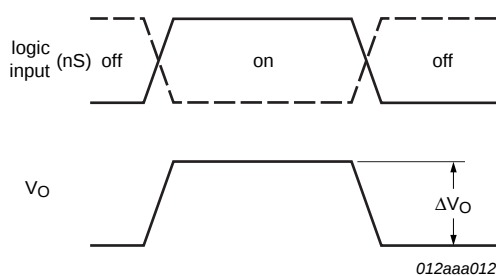


Fig 17. Test circuit for measuring isolation (OFF-state)





a. Test circuit.



b. Input and output pulse definitions

Definition:  $Q_{inj} = \Delta V_O \times C_L$ .

$\Delta V_O$  = output voltage variation.

$R_{gen}$  = generator resistance.

$V_{gen}$  = generator voltage.

**Fig 20. Test circuit for measuring charge injection**

13. Package outline

XQFN10: plastic, extremely thin quad flat package; no leads;  
10 terminals; body 1.40 x 1.80 x 0.50 mm

SOT1160-1

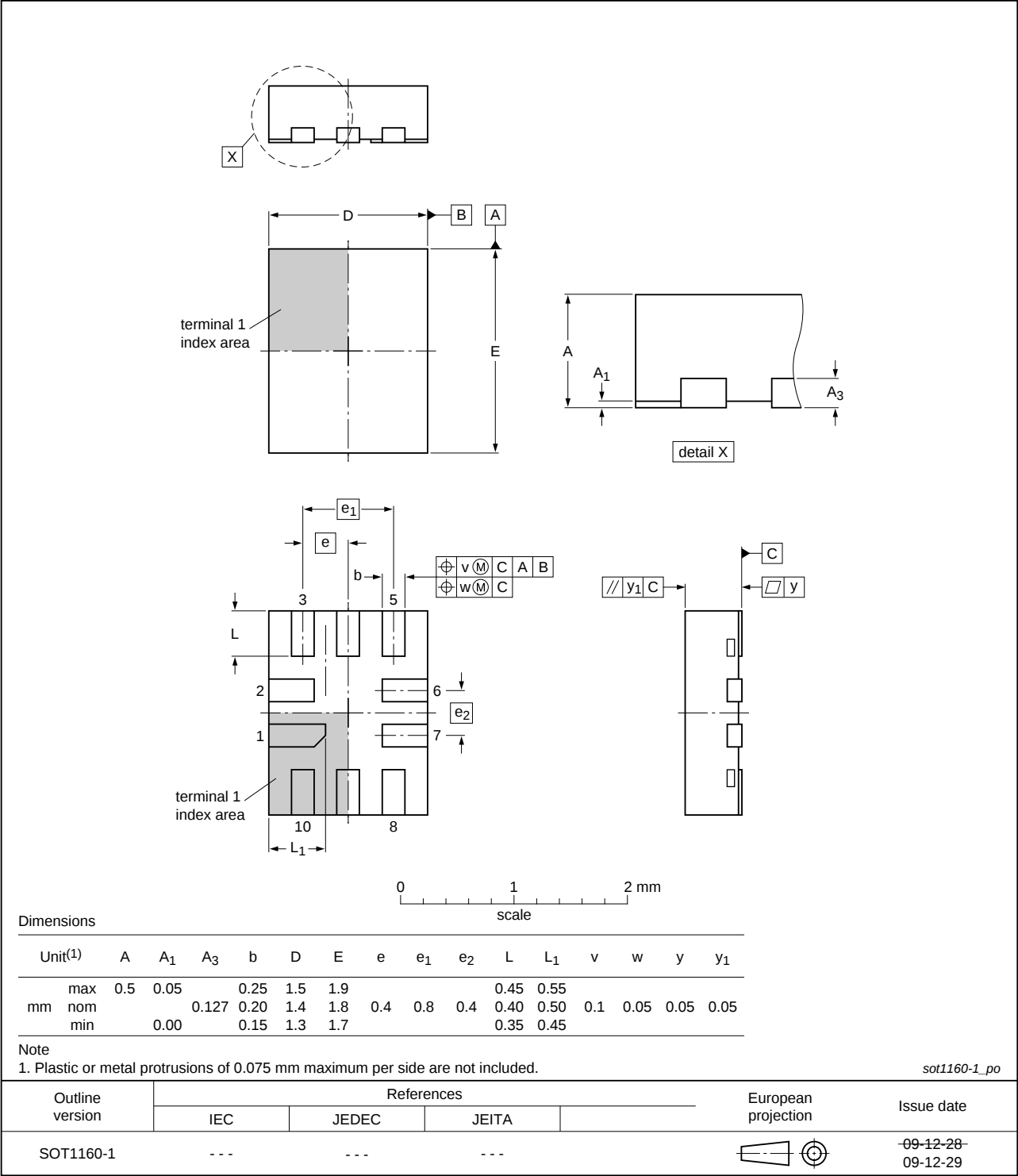


Fig 21. Package outline SOT1160-1 (XQFN10)

## 14. Abbreviations

Table 13. Abbreviations

| Acronym | Description                             |
|---------|-----------------------------------------|
| CDM     | Charged Device Model                    |
| CMOS    | Complementary Metal-Oxide Semiconductor |
| ESD     | ElectroStatic Discharge                 |
| HBM     | Human Body Model                        |
| MM      | Machine Model                           |
| TTL     | Transistor-Transistor Logic             |

## 15. Revision history

Table 14. Revision history

| Document ID    | Release date           | Data sheet status  | Change notice | Supersedes    |
|----------------|------------------------|--------------------|---------------|---------------|
| NX3L2267S v.2  | 20111108               | Product data sheet | -             | NX3L2267S v.1 |
| Modifications: | • Legal pages updated. |                    |               |               |
| NX3L2267S v.1  | 20110823               | Product data sheet | -             | -             |

## 16. Legal information

### 16.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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